NSN 5961-01-100-4677

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-100-4677 **Inclosure Material:** Metal **Overall Length:** Between 0.640 inches and 0.786 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.290 inches and 0.320 inches **Component Name And Quantity:** 2 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 60.0 collector to base voltage, dc all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Special Features:** Item is a pair of unitized quad transistors, each quad has two pnp and two npn transistors **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No